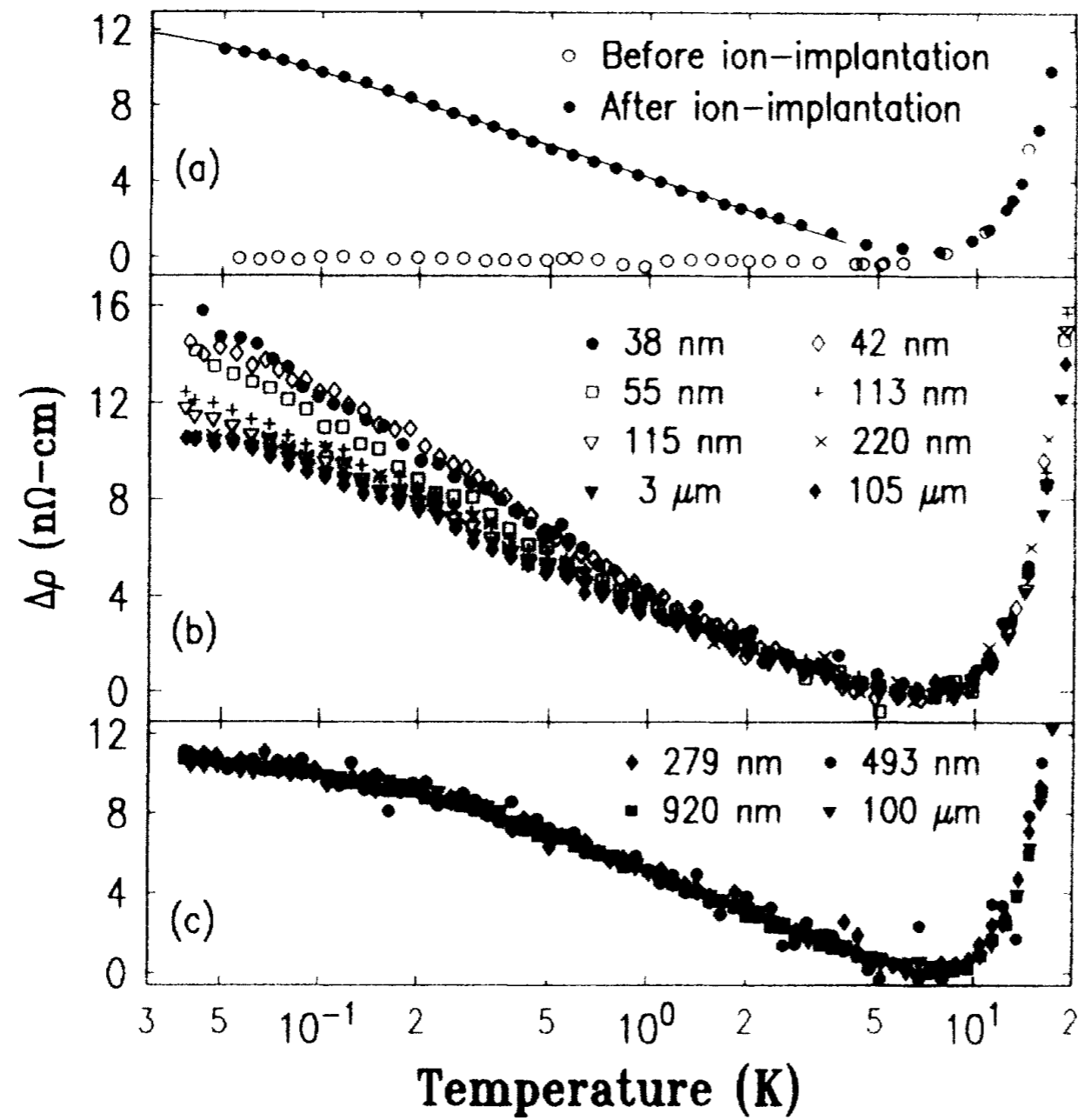


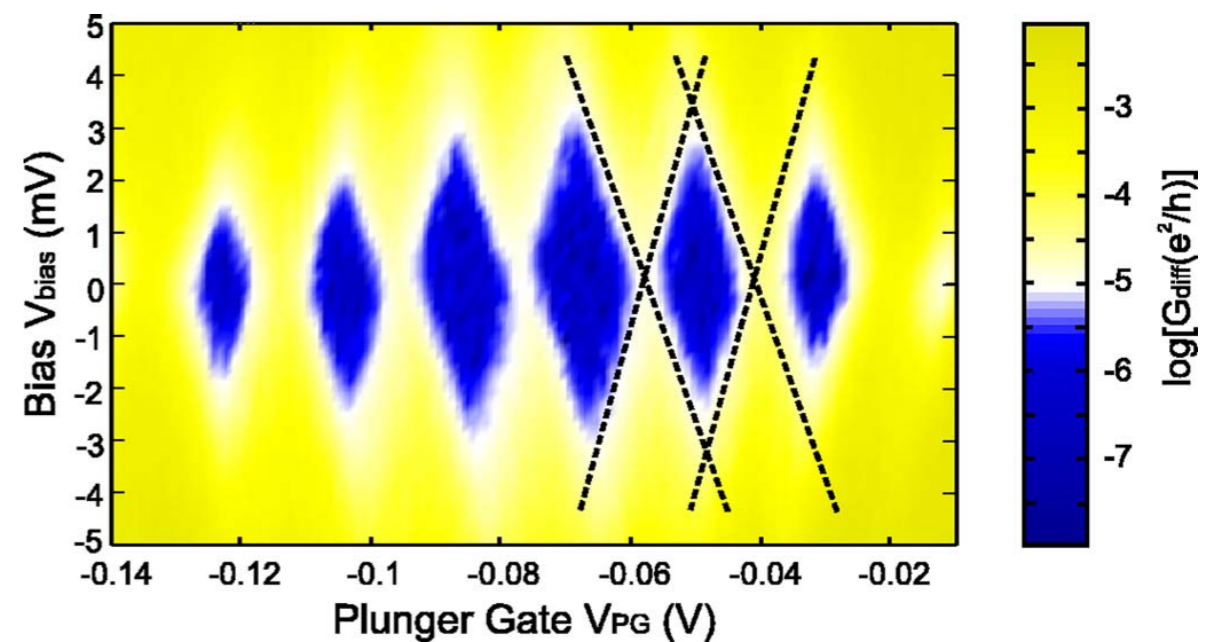
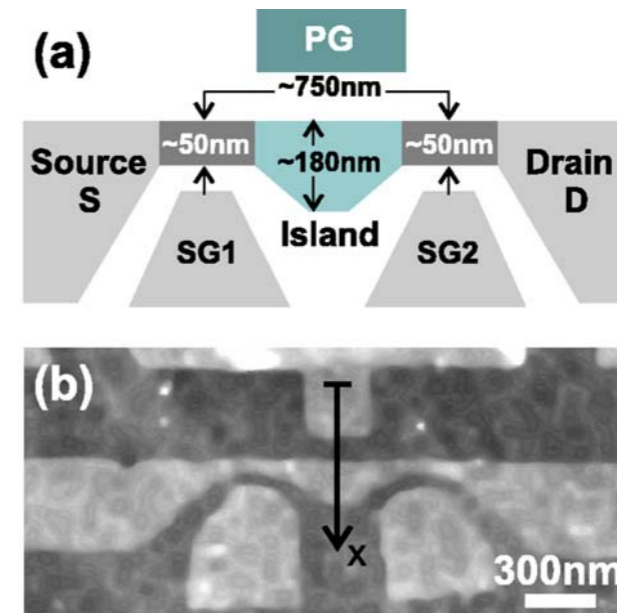
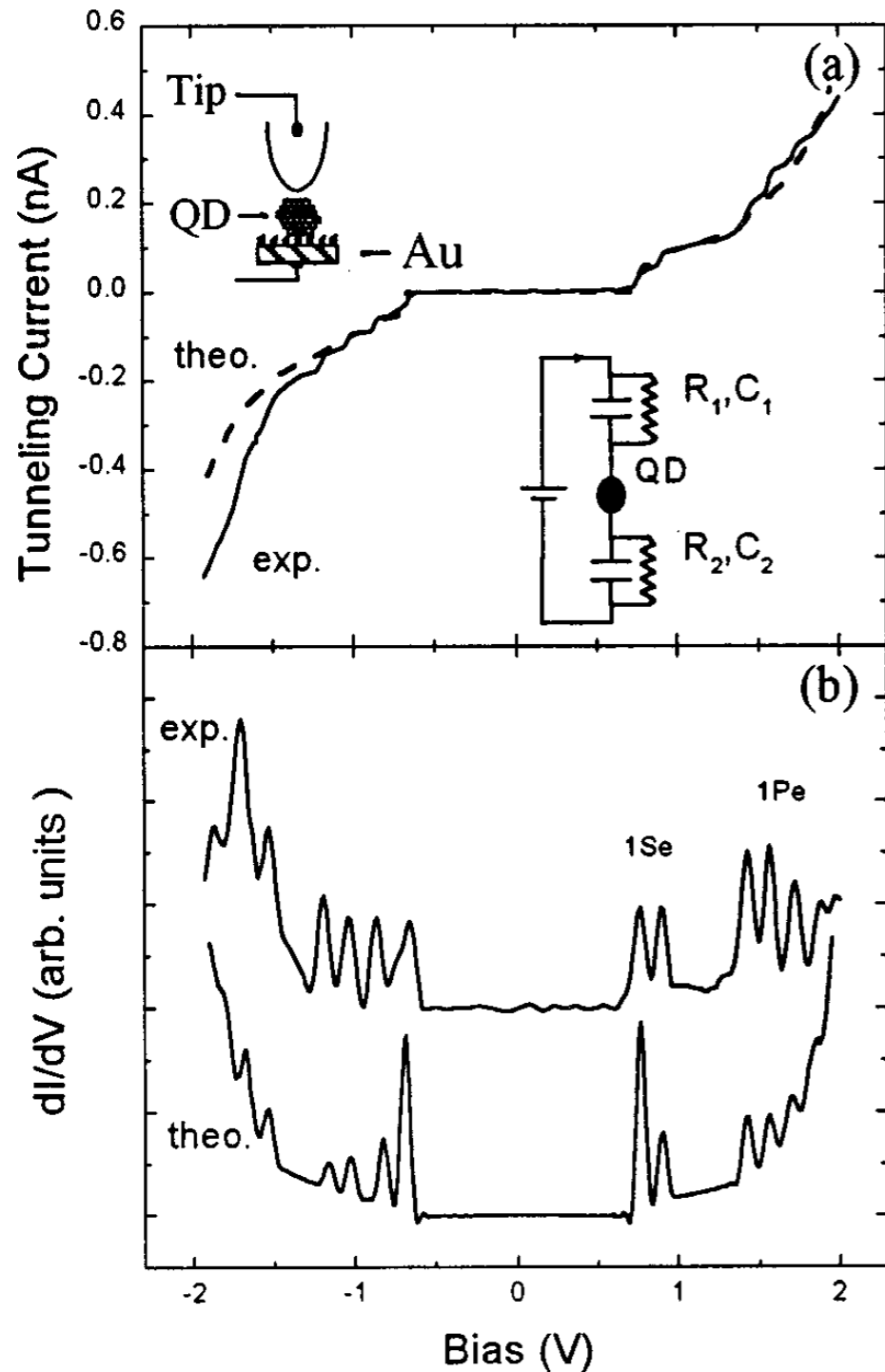
Kondo effect



Tunneling through quantum dots

small dots - resonant tunneling

larger dots - Coulomb blockade

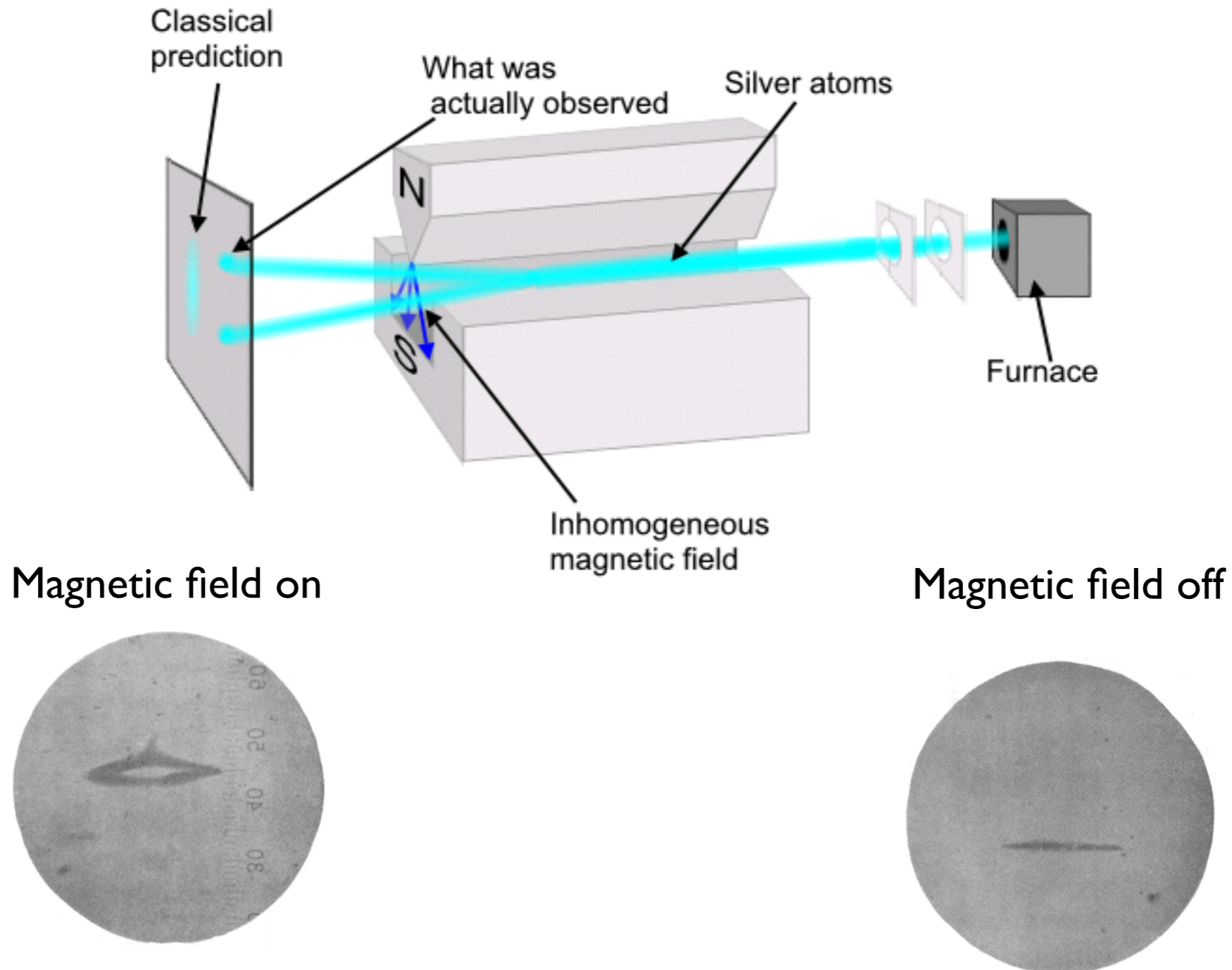


Spin in Stern-Gerlach experiment

Der experimentelle Nachweis der Richtungsquantelung im Magnetfeld.

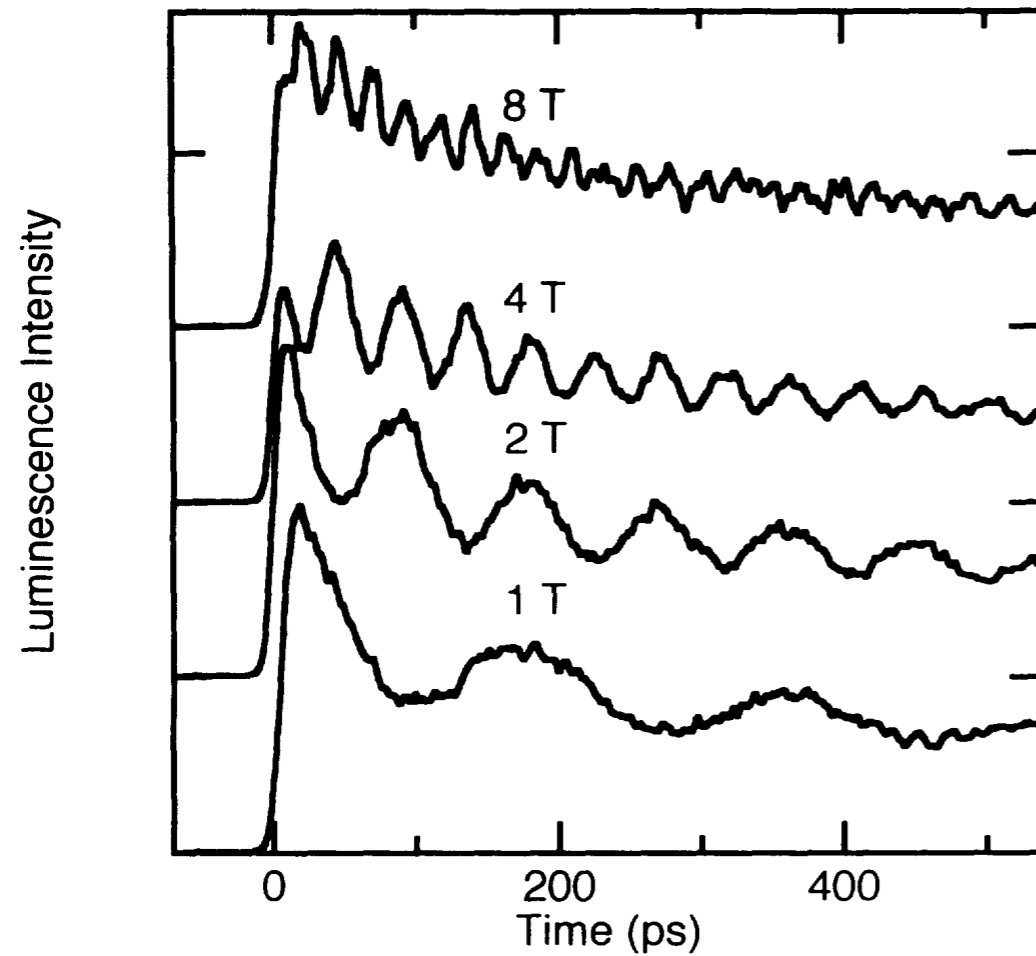
Von **Walther Gerlach** in Frankfurt a. M. und **Otto Stern** in Rostock.

Mit sieben Abbildungen. (Eingegangen am 1. März 1922.)



Spin precession in solid state devices: recombination of photo-excited spin-polarised electrons

$$\Omega_L = g\mu_B B / \hbar = eB / m \cdot g / 2$$



- long spin coherence times (500 ps)
- determination of Lande g-factor (here, on a quantum well)

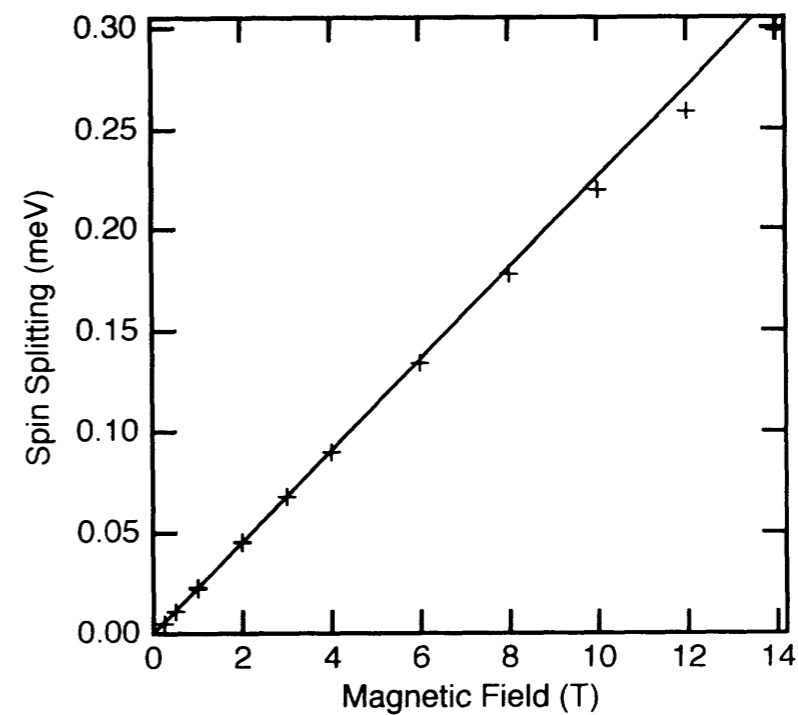
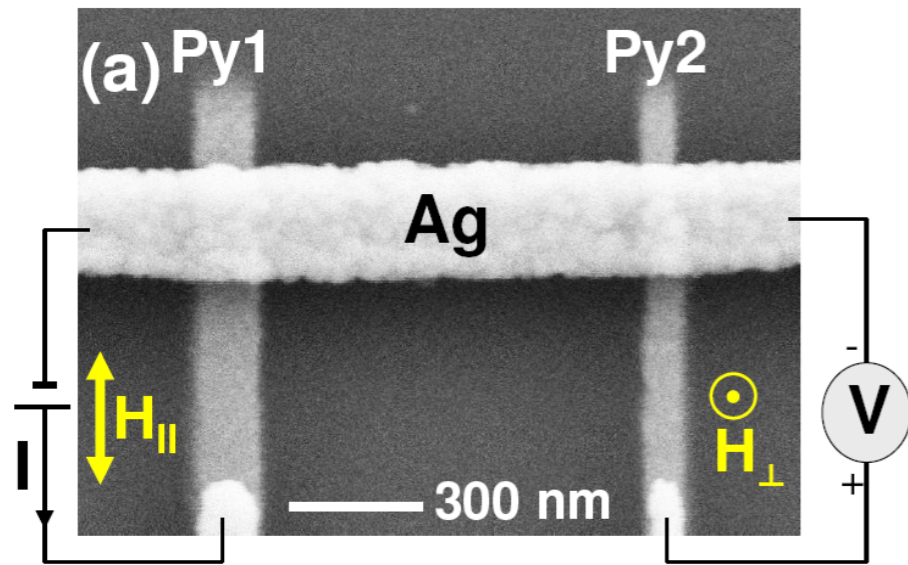
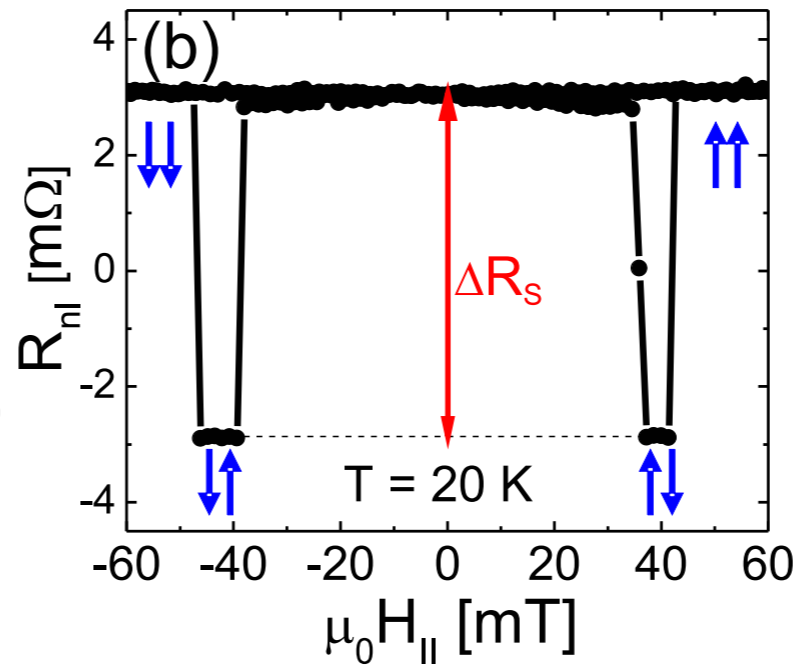


FIG. 4. Dependence of the electron spin splitting on the applied magnetic field (crosses), and spin splitting expected for a constant g factor of -0.390 (line).

Spin precession in solid state devices: Hanle effect



PRL 104, 237202 (2010)

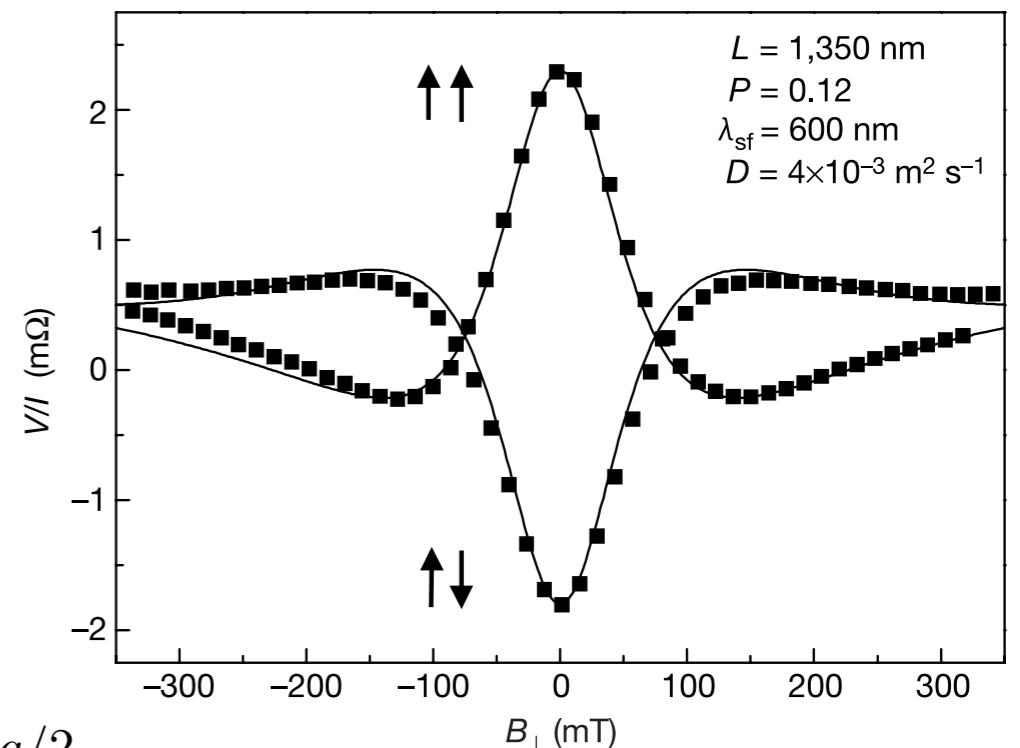


Original idea probably by Johnson & Silsbee, PRL 55, 1790 (1985)

Here from Nature 416, 713 (2002)

$$V(B_{\perp}) = \pm I \frac{p^2}{e^2 N_{Al} A} \int_0^{\infty} P(t) \cos(\omega_L t) \exp(-t/\tau_{sf}) dt$$

$$P(t) = \frac{1}{\sqrt{4\pi Dt}} \exp[-L^2/4Dt] \quad \Omega_L = g\mu_B B/\hbar = eB/m \cdot g/2$$



Topics for the bonus lecture (role of spin in transport):

- multilayers (GMR, TMR...)
- SOI-related effects:
 - ◆ Edelstein effect, SOT
 - ◆ AMR (and AHE)
 - ◆ SHE, QSHE (topological insulators)

Abbreviations explained: giant/tunneling magnetoresistance (GMR/TMR), spin-orbit interaction (SOI), anomalous Hall effect (AHE), anisotropic magnetoresistance (AMR) and (quantum) spin-Hall effect (Q)SHE.